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N-Channel Power MOSFET

800V, 3A, 4.2Ω

FEATURES

- Low $R_{DS(ON)}$ 3.3 Ω (Typ.)
- Low gate charge typical @ 19nC (Typ.)
- Low Crss typical @ 10.2pF (Typ.)
- Improved dv/dt capability

KEY PERFORMANCE PARAMETERS					
PARAMETER	VALUE	UNIT			
V_{DS}	800	V			
R _{DS(on)} (max)	4.2	Ω			
Q_g	19	nC			





APPLICATION

- Power Supply
- Lighting

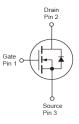








TO-252(DPAK)



Notes: MSL 3 (Moisture Sensitivity Level) for TO-252 (D-PAK) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)							
PARAMETER		SYMBOL					
			IPAK/DPAK	ITO-220	TO-220	UNIT	
Drain-Source Voltage		V _{DS}		800		V	
Gate-Source Voltage		V_{GS}		±30		V	
Continuous Drain Current (Note 1)	$T_C = 25^{\circ}C$		3			Α	
Continuous Drain Current	$T_C = 100$ °C	- I _D	1.83				
Pulsed Drain Current (Note 2)		I _{DM}		12		Α	
Single Pulsed Avalanche Energy (Not	e 3)	E _{AS}		48		mJ	
Single Pulsed Avalanche Current (No	te 3)	I _{AS}		3		Α	
Repetitive Avalanche Energy (Note 3)		E _{AR}		9.4		mJ	
Repetitive Avalanche Energy ^(Note 4)		dV/dt	4.5		V/ns		
Total Power Dissipation @ T _C = 25°C		P _{DTOT}	94	32	94	W	
Operating Junction and Storage Ten	nperature Range	T _J , T _{STG}	- :	55 to +150		°C	

THERMAL PERFORMANCE						
PARAMETER	CVMPOL					
PARAMETER	SYMBOL	IPAK/DPAK	ITO-220	TO-220	UNIT	
Junction to Case Thermal Resistance	R _{eJc}	1.33	3.9	1.33	°C/W	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	110	62	.5	°C/W	

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air



ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 5)		<u>.</u>				
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	800			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	V _{GS(TH)}	2		4	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 800V, V_{GS} = 0V$	I _{DSS}			10	μΑ
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 1.5A$	R _{DS(ON)}		3.3	4.2	Ω
Forward Transfer Conductance	$V_{DS} = 30V, I_D = 1.5A$	g _{fs}		3.7		S
Dynamic (Note 6)						
Total Gate Charge		Q_g		19		
Gate-Source Charge	$V_{DS} = 640V, I_D = 3A,$	Q_{gs}		4		nC
Gate-Drain Charge	$V_{GS} = 10V$	Q_{gd}		7.6		
Input Capacitance		C _{iss}		696		
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	C _{oss}		65		рF
Reverse Transfer Capacitance		C _{rss}		10.2		
Gate Resistance	F = 1MHz, open drain	R_g		3.2		Ω
Switching (Note 7)						
Turn-On Delay Time		t _{d(on)}		48		
Turn-On Rise Time	$V_{GS} = 10V, I_D = 3A,$	t _r		36		
Turn-Off Delay Time	$V_{DD} = 400V, R_{G} = 25\Omega$	t _{d(off)}		106		ns
Turn-Off Fall Time		t _f		41		
Source-Drain Diode (Note 5)		<u>.</u>				
Source Current	Integral reverse diode	Is			3	Α
Source Current (Pulse)	in the MOSFET	I _{SM}			12	Α
Diode Forward Voltage	$I_S = 3A$, $V_{GS} = 0V$	V _{SD}			1.5	V
Reverse Recovery Time	$V_{GS} = 0V, I_S = 3A,$	t _{rr}		370		ns
Reverse Recovery Charge	$dI_F/dt = 100A/us$	Q _{rr}		1.8		μC

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 10mH, $I_{AS} = 3A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 4. $I_{SD} \le 3A$, $dI/dt \le 200A/uS$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$
- 5. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%
- 6. For DESIGN AID ONLY, not subject to production testing.
- 7. Switching time is essentially independent of operating temperature.



ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM3N80CZ C0G	TO-220	50pcs / Tube
TSM3N80CI C0G	ITO-220	50pcs / Tube
TSM3N80CH C5G	TO-251 (IPAK)	75pcs / Tube
TSM3N80CP ROG	TO-252 (DPAK)	2,500pcs / 13" Reel

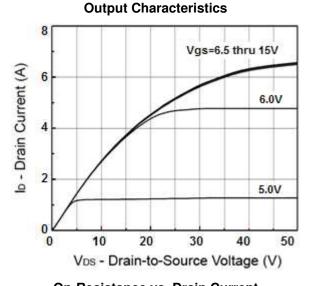
Note:

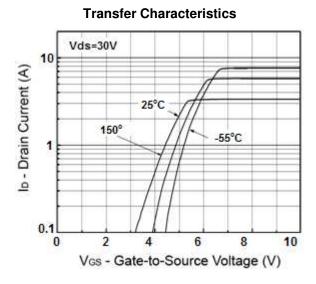
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition

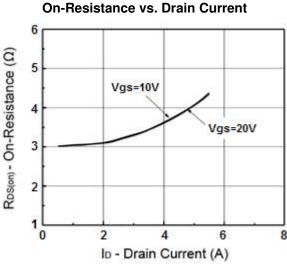


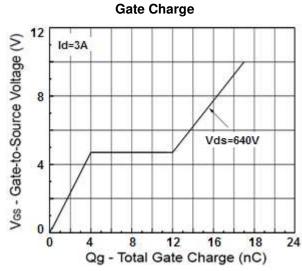
CHARACTERISTICS CURVES

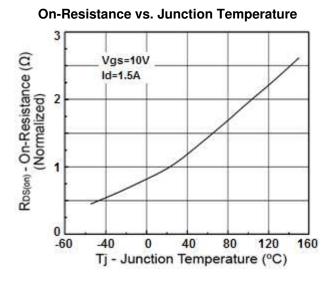
 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

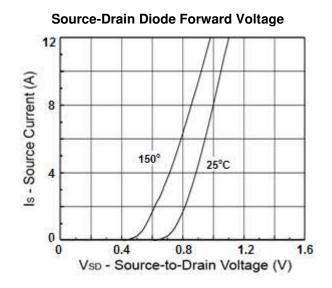








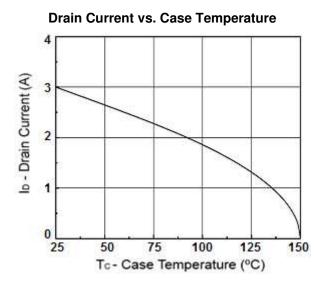






CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$



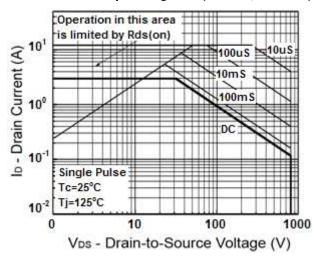
BV_{DSS} vs. Junction Temperature

1.2
Vgs=0V
Id=250uA

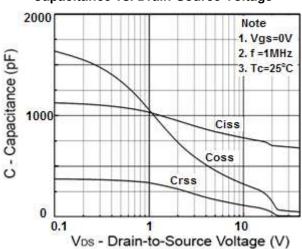
0.8

-60
40
0
40
80
120
160
Tj - Junction Temperature (°C)

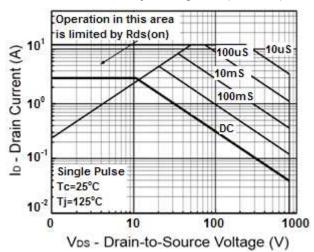
Maximum Safe Operating Area(TO-220, I/D-PAK)



Capacitance vs. Drain-Source Voltage



Maximum Safe Operating Area(ITO-220)

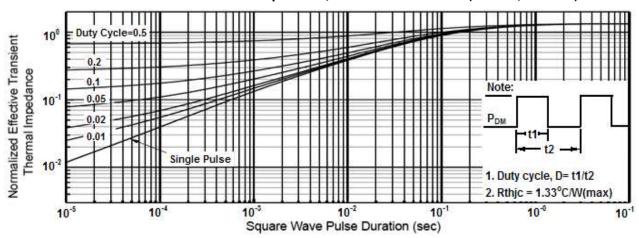




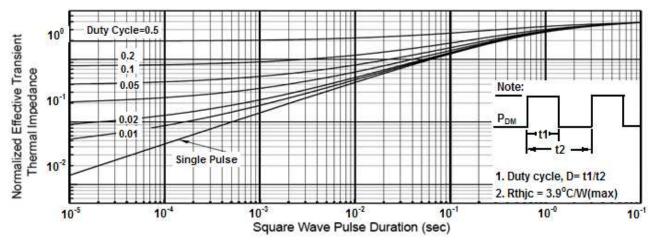
CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

Normalized Thermal Transient Impedance, Junction-to-Ambient (TO-220, I/D-PAK)

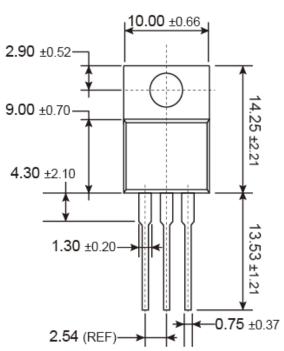


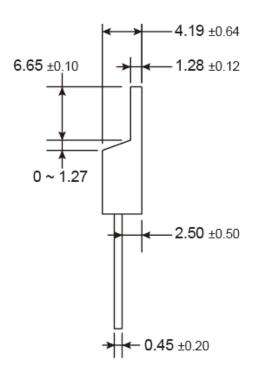
Normalized Thermal Transient Impedance, Junction-to-Ambient (ITO-220)











MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

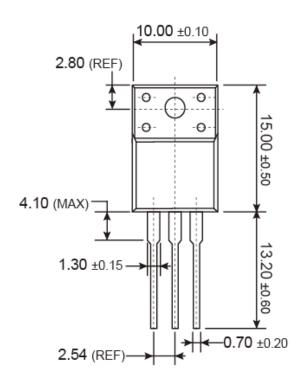
 $S = May \quad T = Jun \quad U = Jul \quad V = Aug$

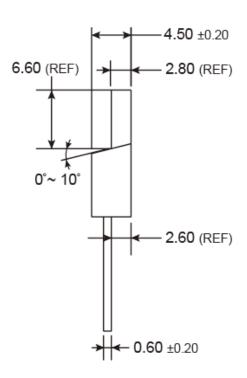
W = Sep X = Oct Y = Nov Z = Dec

L = Lot Code $(1\sim9, A\sim Z)$

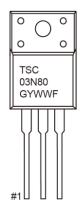


ITO-220





MARKING DIAGRAM



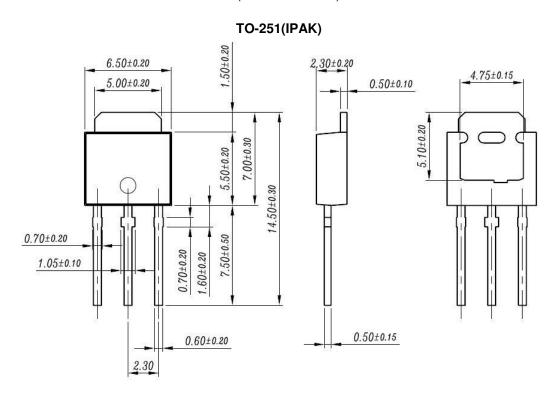
G = Halogen Free

Y = Year Code

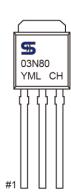
WW = Week Code $(01 \sim 52)$

F = Factory Code





MARKING DIAGRAM



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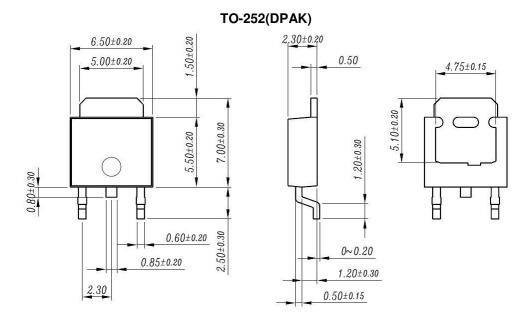
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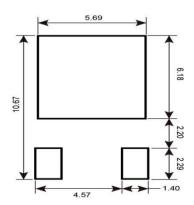
W =Sep **X** =Oct **Y** =Nov **Z** =Dec

 $\mathbf{L} = \text{Lot Code } (1 \sim 9, A \sim Z)$

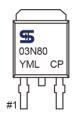




SUGGESTED PAD LAYOUT (Unit: Millimeters)



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L = Lot Code $(1\sim9, A\sim Z)$







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